

## Features

- Split Gate Trench MOSFET Technology
- High Density Cell Design For Low  $R_{DS(ON)}$
- Moisture Sensitivity Level 3
- Halogen Free. "Green" Device<sup>(Note 1)</sup>
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

## N-CHANNEL MOSFET

## Maximum Ratings

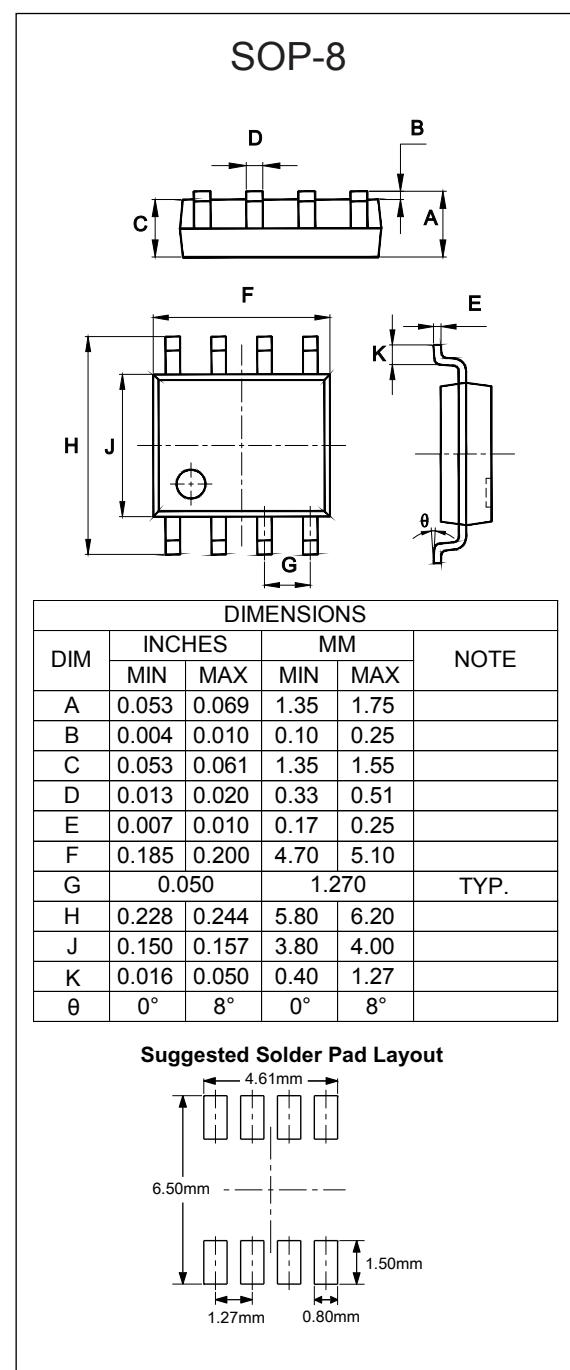
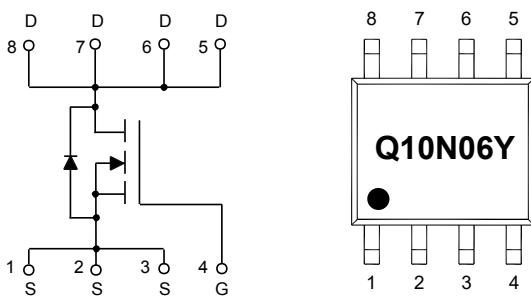
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 65°C/W Junction to Ambient<sup>(Note 2)</sup>

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	$V_{DS}$	60	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current $T_A=25^\circ\text{C}$	$I_D$	10	A
		6.3	
Pulsed Drain Current <sup>(Note 3)</sup>	$I_{DM}$	40	A
Total Power Dissipation <sup>(Note 4)</sup>	$P_D$	1.9	W
Single Pulsed Avalanche Energy <sup>(Note 5)</sup>	$E_{AS}$	40	mJ

Note:

1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. The value of  $R_{\theta JA}$  is measured with the device mounted on 1in<sup>2</sup> FR-4 board with 2oz. Copper, in a still air environment with  $T_A=25^\circ\text{C}$ .
3. Repetitive rating; pulse width limited by max. junction temperature.
4.  $P_D$  is based on max. junction temperature, using junction-ambient thermal resistance.
5.  $T_J=25^\circ\text{C}$ ,  $V_{DD}=50\text{V}$ ,  $V_{GS}=10\text{V}$ ,  $L=0.5\text{mH}$ .

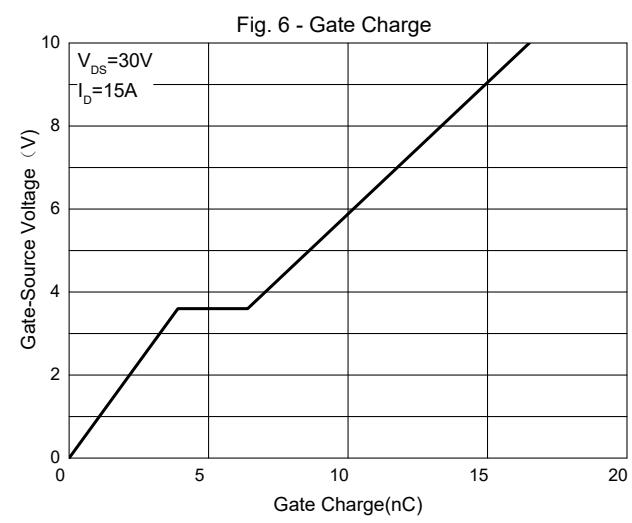
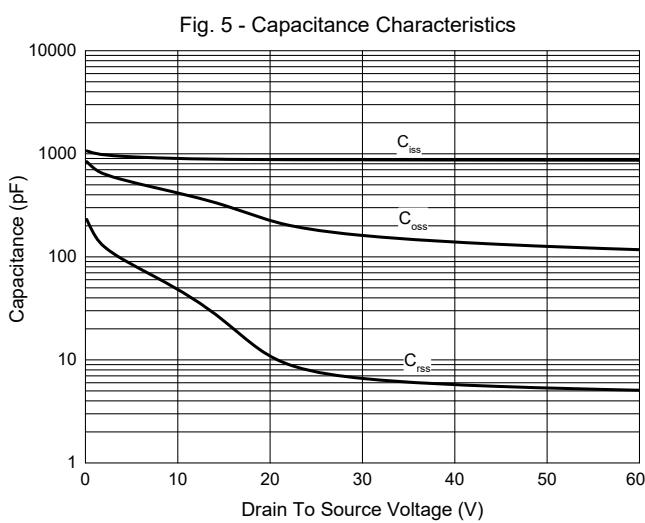
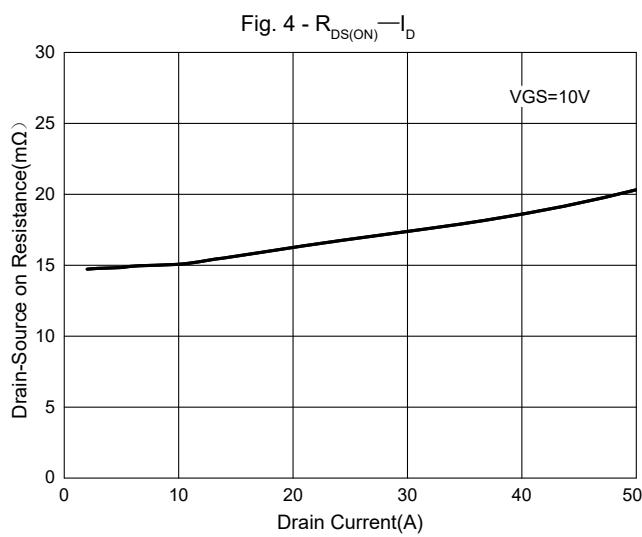
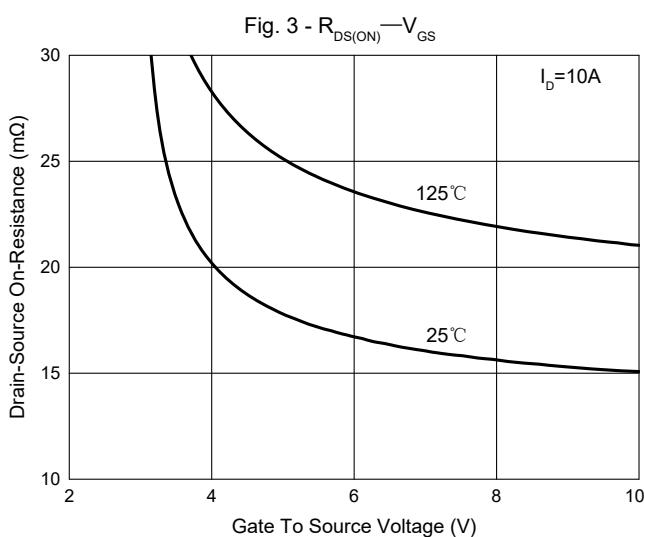
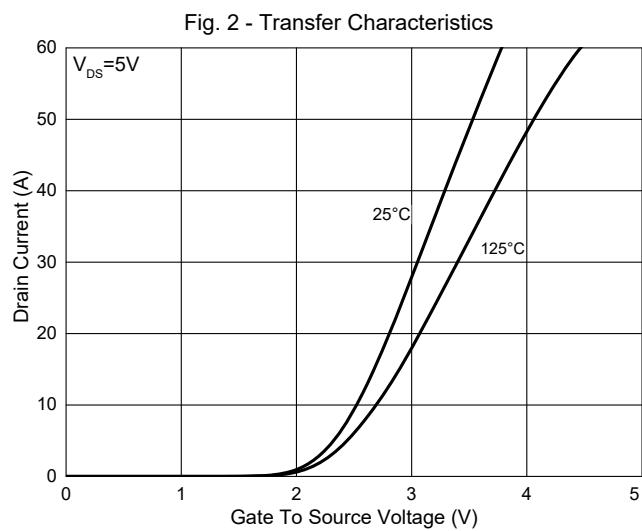
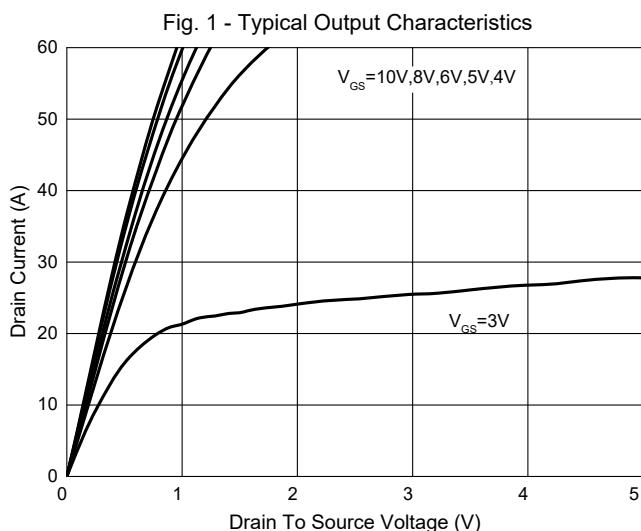
## Internal Structure and Marking Code



**Electrical Characteristics @ 25°C (Unless Otherwise Specified)**

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
<b>Static Characteristics</b>						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	60			V
Gate-Source Leakage Current	$I_{GSS}$	$V_{DS}=0V, V_{GS} = \pm 20V$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=60V, V_{GS}=0V$			1	$\mu A$
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1.0	1.4	2.5	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=10A$		15	19	$m\Omega$
		$V_{GS}=4.5V, I_D=5A$		17	22	
Gate Resistance	$R_g$	f=1 MHz, Open drain		1.6		$\Omega$
<b>Diode Characteristics</b>						
Continuous Body Diode Current	$I_S$				10	A
Diode Forward Voltage	$V_{SD}$	$V_{GS}=0V, I_S=10A$			1.2	V
Reverse Recovery Time	$t_{rr}$	$I_F=15A, dI_F/dt=100A/\mu s$		25		ns
Reverse Recovery Charge	$Q_{rr}$			9.5		nC
<b>Dynamic Characteristics</b>						
Input Capacitance	$C_{iss}$	$V_{DS}=30V, V_{GS}=0V, f=1MHz$		873		$pF$
Output Capacitance	$C_{oss}$			159		
Reverse Transfer Capacitance	$C_{rss}$			6.5		
Total Gate Charge	$Q_g$	$V_{DS}=30V, V_{GS}=10V, I_D=15A$		16.5		$nC$
Gate-Source Charge	$Q_{gs}$			3.9		
Gate-Drain Charge	$Q_{gd}$			2.5		
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=30V, V_{GS}=10V, I_{DS}=15A, R_G=3\Omega$		3.4		$ns$
Turn-On Rise Time	$t_r$			40		
Turn-Off Delay Time	$t_{d(off)}$			18		
Turn-Off Fall Time	$t_f$			6.6		

## Curve Characteristics



## Curve Characteristics

Fig. 7 - Normalized Threshold Voltage

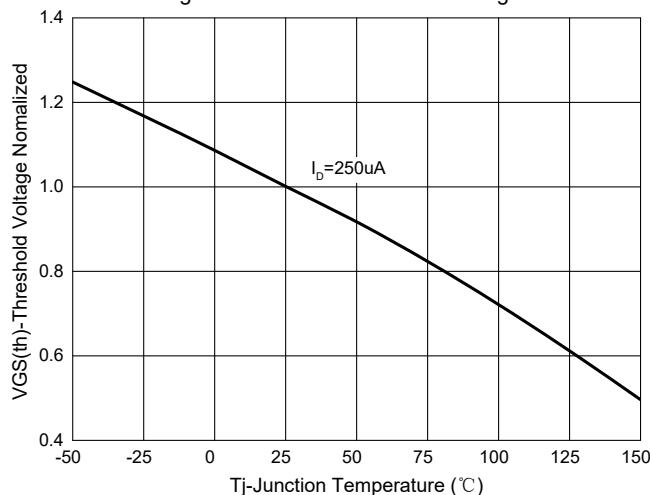


Fig.8-Normalized On Resistance Characteristics

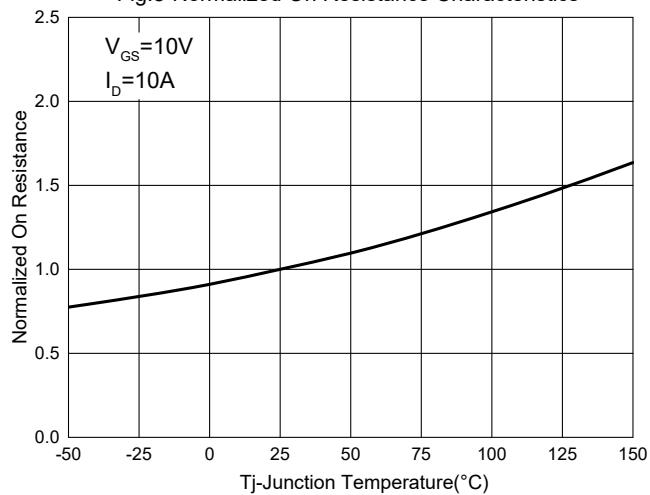


Fig.9 - I<sub>S</sub>—V<sub>SD</sub>

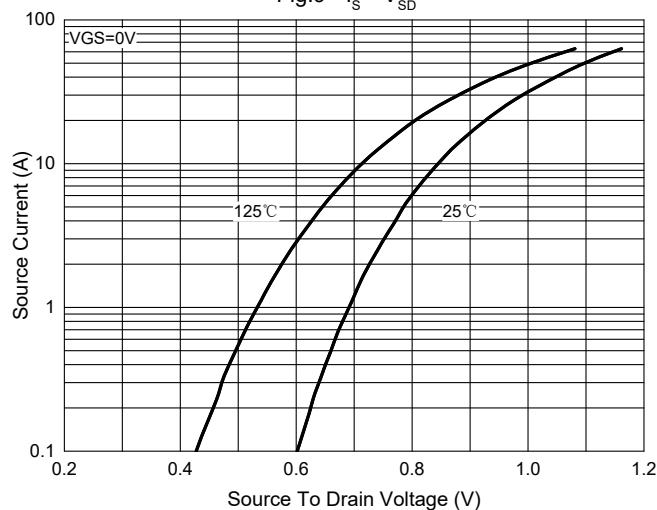


Fig. 10 - Drain Current

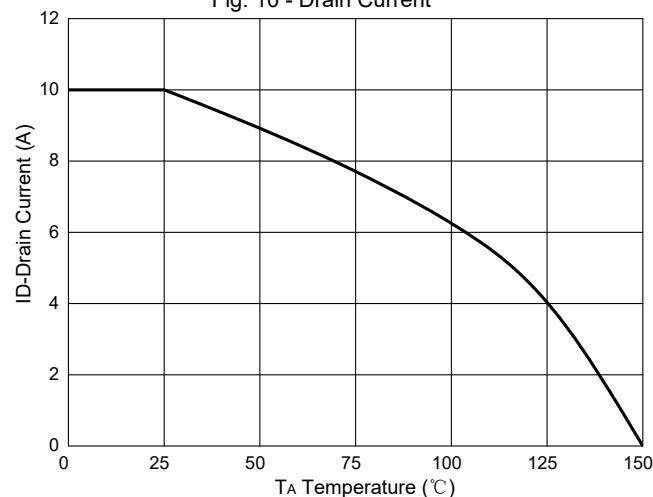
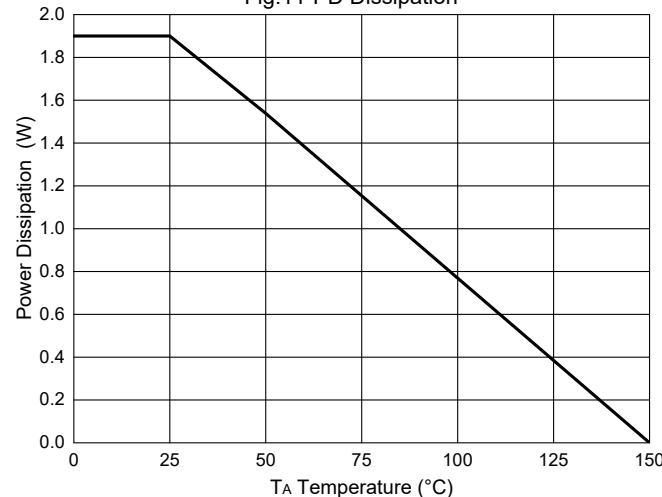
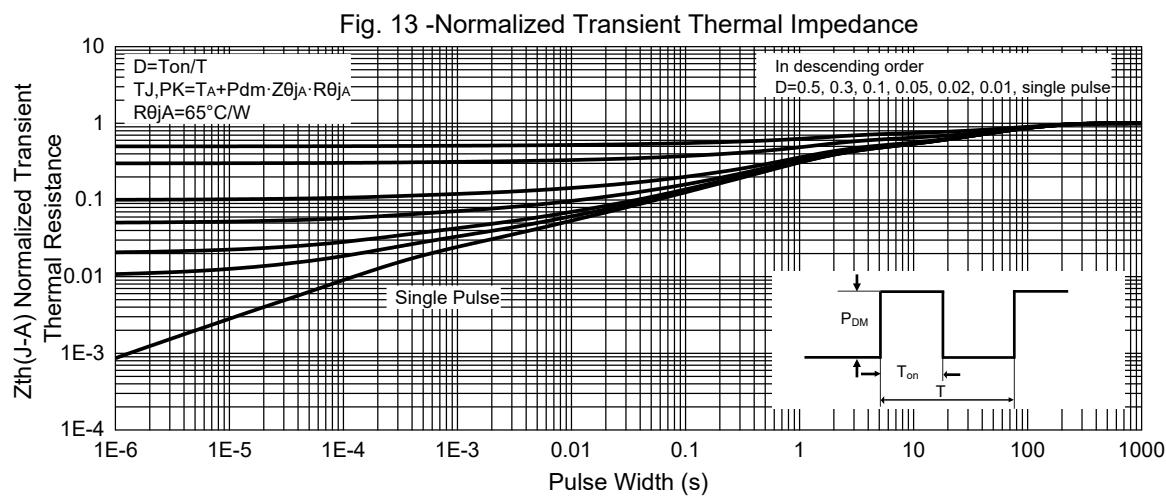
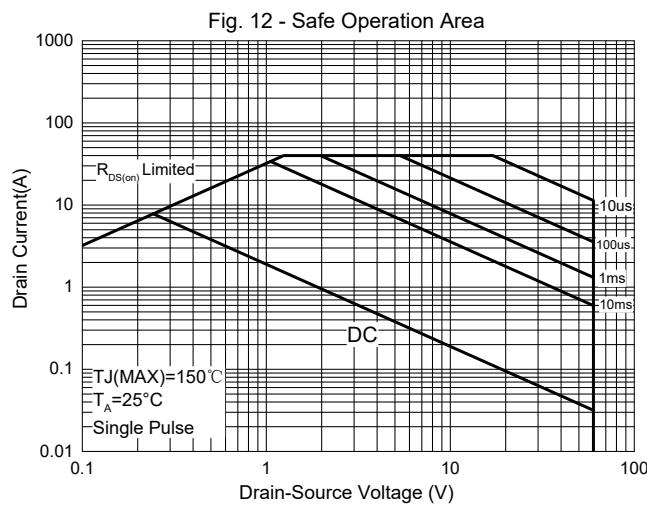


Fig.11-PD Dissipation



## Curve Characteristics



## Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 4Kpcs/Reel

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